

INFRARED DIODE LASER AT 1060nm

RN-XF-1060/2500~5000mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy operation.

They are used in measurement, communication, spectrum analysis, etc.

产品参数

RN-XF-1060/2500~5000mW			
Central wavelength (nm)	1064±20N		
Operating mode	>1500, 1600, ... , 2500		
Output power (mW)	Multimode		
Power stability (rms, over 4 hours)	CW		
Transverse mode	<1%, <3%, <5%		
Dimensions of beam at the aperture (mm)	<5		
Beam divergence, full angle (mrad)	<20		
Warm-up time (minutes)	<3. 0		
Beam height from base plate (mm)	~5×8		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-H-LED	PSU-H-FDA	PSU-H-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty period	1 year		